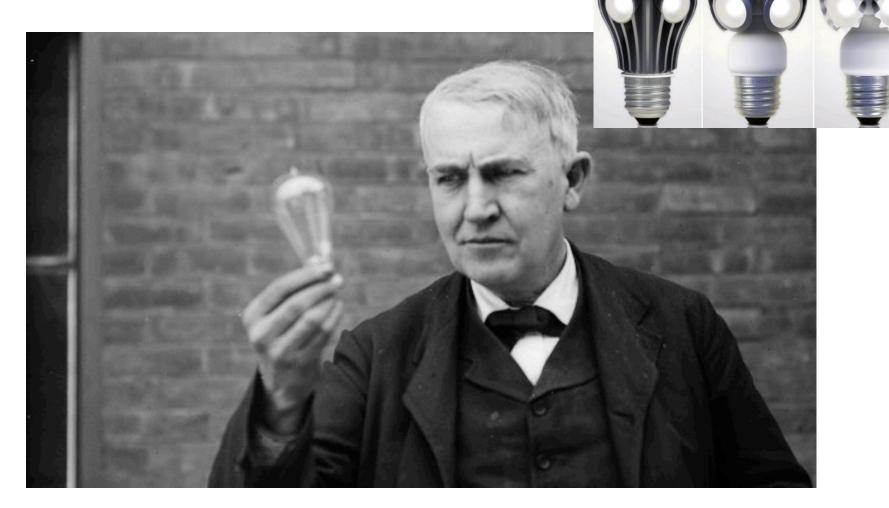
1 Lecture 10 – Emitters/Detectors

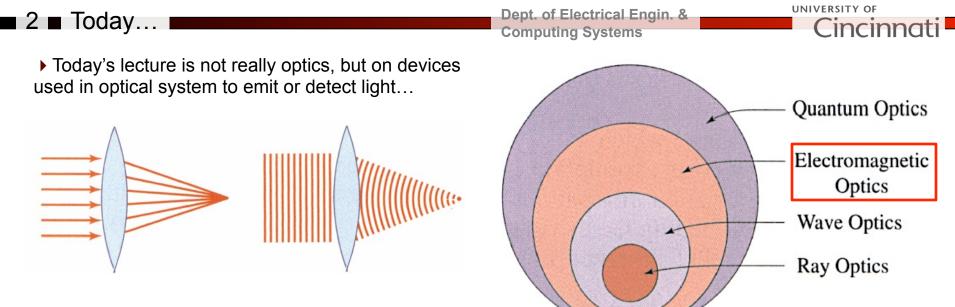
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10 – Emitters/Detectors







Credit: Fund. Photonics – Fig. 2.3-1

Credit: Fund. Photonics – Fig. 1.0-1

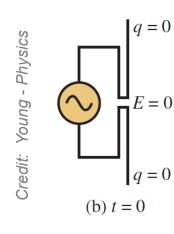
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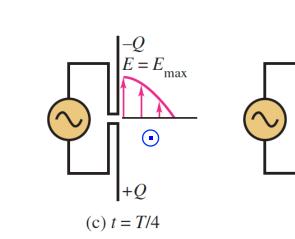
Topics related to Emitters

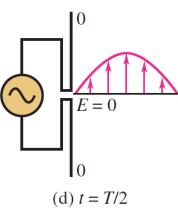
- mechanisms for light emission
- absorbance leading to fluorescence (related to the lab)
- devices for light emission (focus on those most used in optics)
- optics of LEDS
- Topics related to Detectors
 - common types of detectors
 - performance comparison (how to select the right detector for your project)

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3 ■ How A Photon is Created

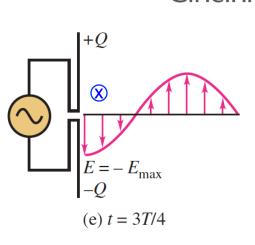






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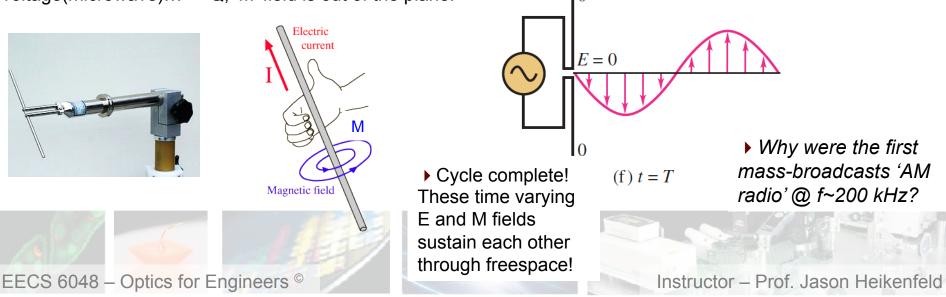


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 Consider a simple dipole antenna with two wires each about λ/4 long attached to a 10 GHz sinusoidal voltage(microwave)... The voltage hits its 1st positive maximum in ¼ the period, notice the E-field from + to – direction. As current flows 'down' to create the +/-Q, 'M' field is out of the plane.

In ½ the period
V and E = 0
again.

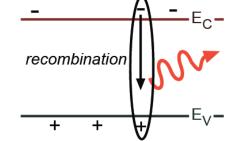
► The voltage hits its first negative max in ³/₄ the period, Efield from + to – direction. As current flows 'up' to create the +/-Q, 'M' field is into the plane.



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> So how are visible and infra-red photons created? Any guesses? What do we need fundamentally to occur?





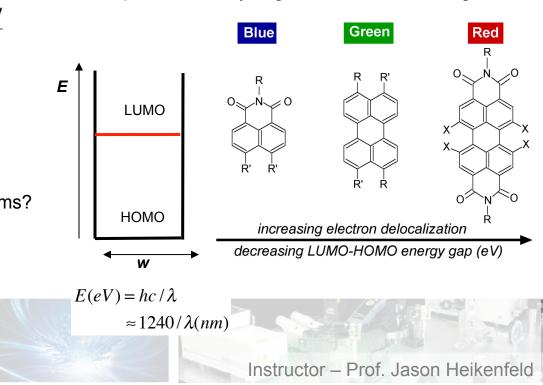
• Other common sources are 'atomic' or 'molecular' transitions... What are they?

13.6 eV (^{2}H) D Hydrogen e Ne is our laser source in the lab! Kr How excite the atoms? Hg Ne H20 Xe astrographics.com EECS 6048 – Optics for Engineers ©

✤ For semiconductors, also have electric charge that moves and creates E&M fields as it does so!

...but, works only if the bandgap is "direct" (same momentum for electrons and holes). If is indirect, then they have to 'change direction' somehow, requiring momentum transfer to the crystal lattice (phonons = vibrations = heat).

In a molecule, you have a highest occupied
'MO' (molecular orbital for electrons) and a lowest
<u>unoccupied</u> MO. Why larger molecules emit longer λ?

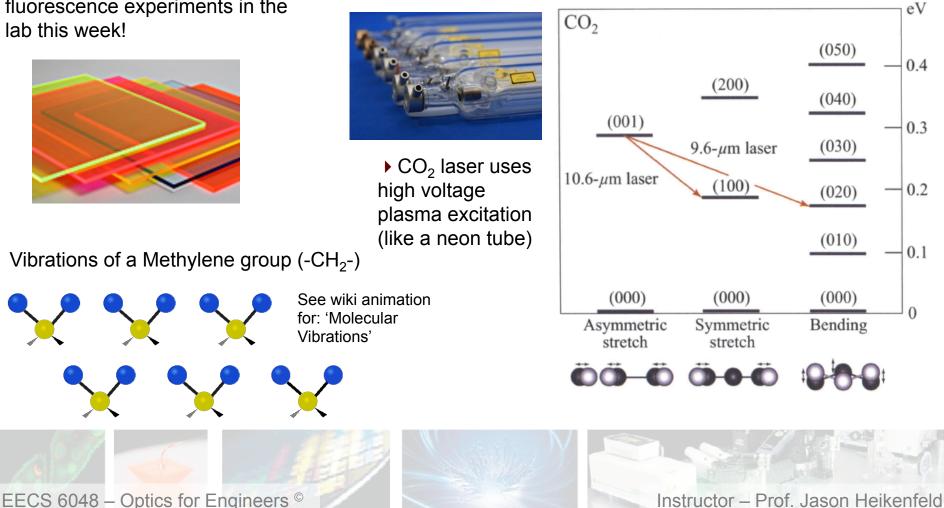


5 Molecules That Emit Light

Lets look at molecular light emission in detail, because:

- it is used frequently in medical imaging, chemistry, etc...

- we will be performing fluorescence experiments in the lab this week!



levels):

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therefore we are transitioning between two energy states...

modes (and even within that mode, there are different energy

• We know that with light emission, energy is lost ALWAYS and

▶ For a molecule, the energy states can have different vibrational

UNIVERSITY OF incin 6 Molecules That Emit Light

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Some organic dyes are VERY large (like orange Rhodamine, image/photo below) and they have a vast array of energy states (makes sense, more ways to twist/turn/increase-decrease energy).

AND the molecule is subject to its surrounding environment (other molecules charges etc.) which can broaden the emission spectrum!

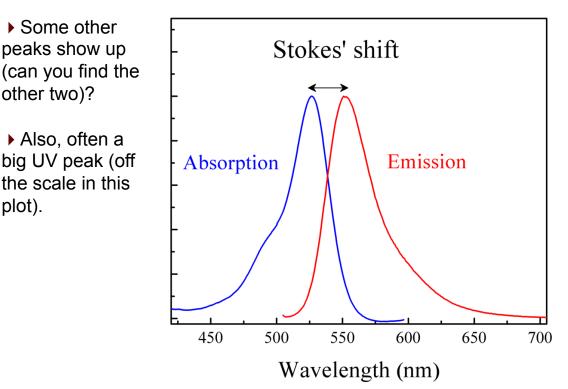
Notice how absorption peak is shifted from emission peak!

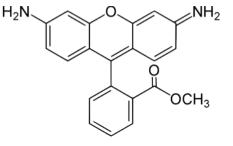
Also, often a big UV peak (off the scale in this plot).

Some other

peaks show up

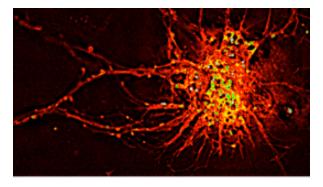
other two)?





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Mitochondria of neuron revealed by staining with a rhodamine 123 derivative

Expert Reviews in Molecular Medicine © 2002 Cambridge University Press



More on Light and Molecules

▶ In this course we deal mainly with visible and UV absorptions...

- Electronic transitions

• Thermal infrared wavelengths are absorbed due to...

- Molecular vibrations

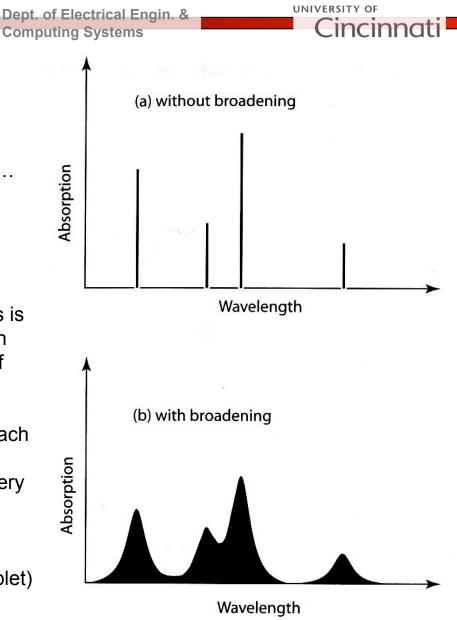
Microwave and far-IR wavelengths...

- Molecular rotations

Why is a microwave oven 2.45 GHz (10.2 cm)? This is also why submarines cannot radio communicate when fully submerged, and why they use SONAR instead of RADAR!

► Again, if it were not for molecules interacting with each other (colliding, vibrating next to each other, E-field interactions, etc.) the emission/absorption would be very narrow.

Top plot: for a single molecule (like humidity in air). Bottom plot: for an ensemble of molecules (like a droplet)



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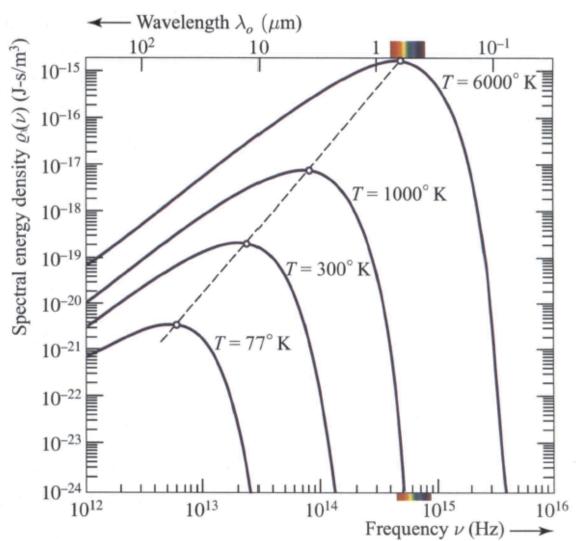
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Credit: Fund. Photonics

 Blackbody radiation.
When you heat up a solid material you create more phonons (lattice vibration).
Eventually many phonons locally can add up to a photon energy.

Is extremely smooth in spectral output. How is that useful?





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9 ■ Review! Take a break!

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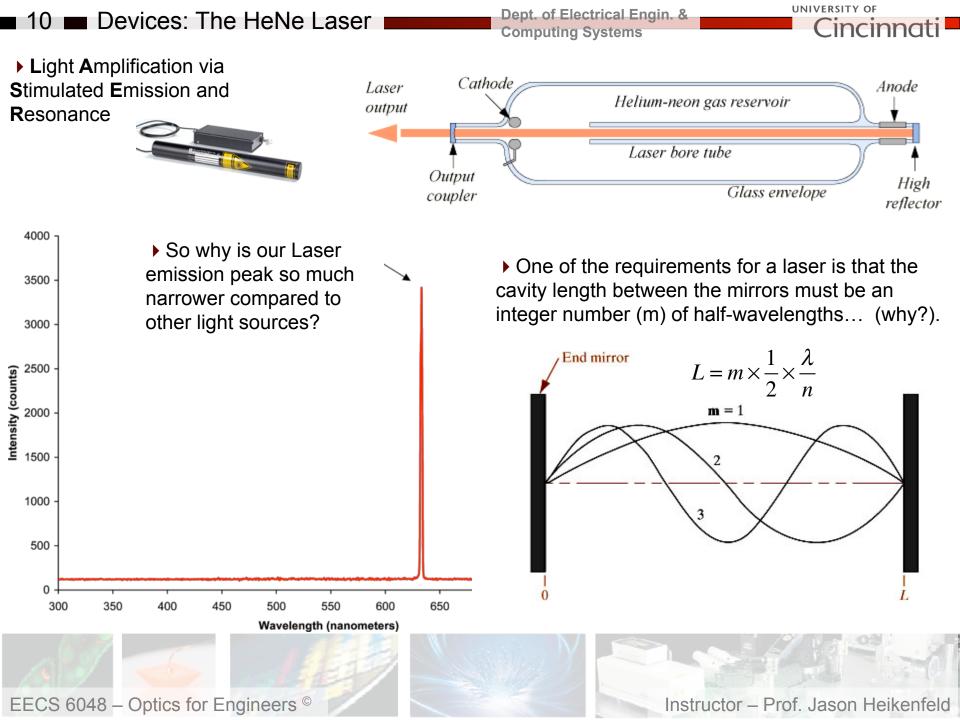
- ► Do materials such as fluorescent dyes and phosphors absorb light most strongly at the same wavelength that they emit? Or not? What is this called?
- (a) Yes / fluorescence.
- (b) No / fluorescence.
- (c) Yes / Stokes shift.
- (d) No / Stokes shift.

Whew! Lets take a quick break!





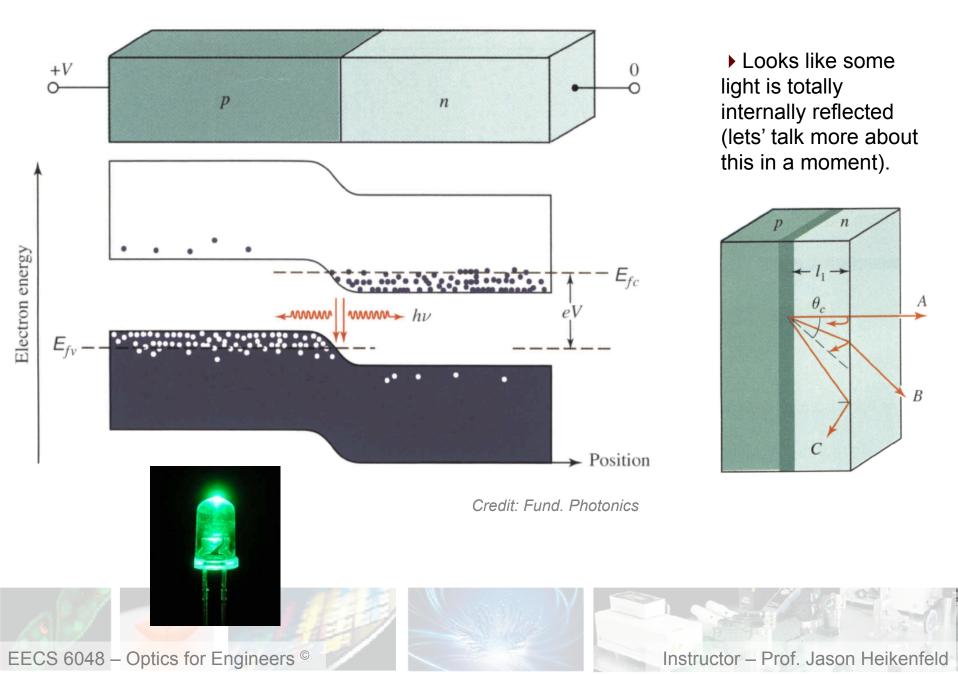






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12 Devices: White LEDs

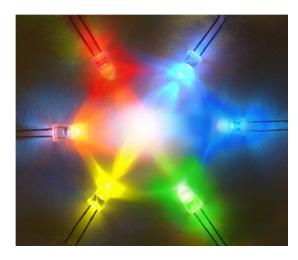
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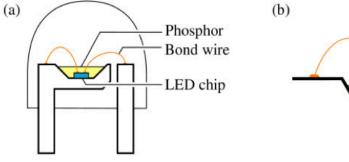
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Prof. Fred Schubert (RPI)

http://www.rpi.edu/~schubert/

So, how do they make white LEDs?





(b) Phosphorescence Blue luminescence Phosphor

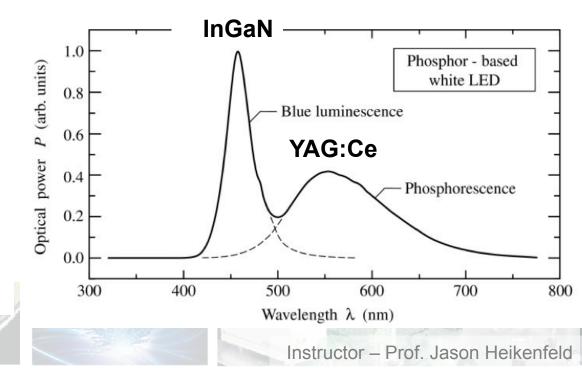
Fig. 12.5. (a) Structure of white LED consisting of a GaInN blue LED chip and a phosphor-containing epoxy encapsulating the semiconductor die. (b) Wavelength-converting phosphorescence and blue luminescence (after Nakamura and Fasol, 1997).



Cree XR-E

So, your local art museum switches to these type of white LEDs and the patrons say all the art looks terrible (colors are off a bit). Why? How fix?

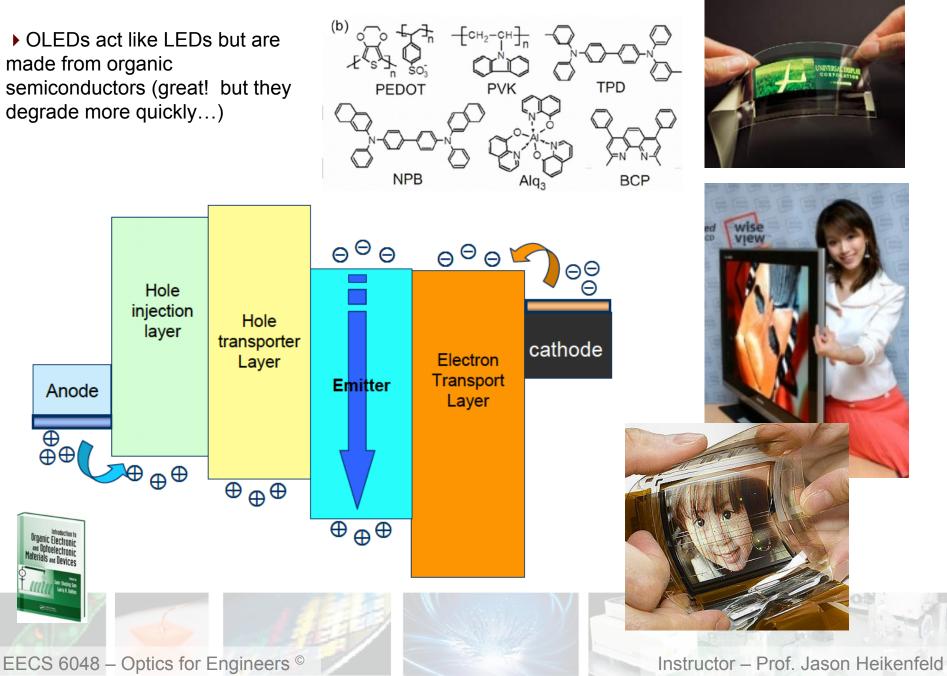
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■ 13 ■ Devices: Organic LEDs (OLEDs)

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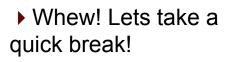
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■ 14 ■ Review! Take a break!

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- A typical white LED is made of:
- (a) A blue LED and a yellow phosphor.
- (b) At least a mix of red, green, and blue LEDs.
- (c) A black LED with white paint over it.
- (d) Magic.
- The output of a LASER is:
- (a) Coherent, all photons are in phase.
- (b) Very narrow in spectral width compared to an LED.
- (c) Highly directional.
- (d) All the above.









■15■ "Brightness' of Lighting & Displays

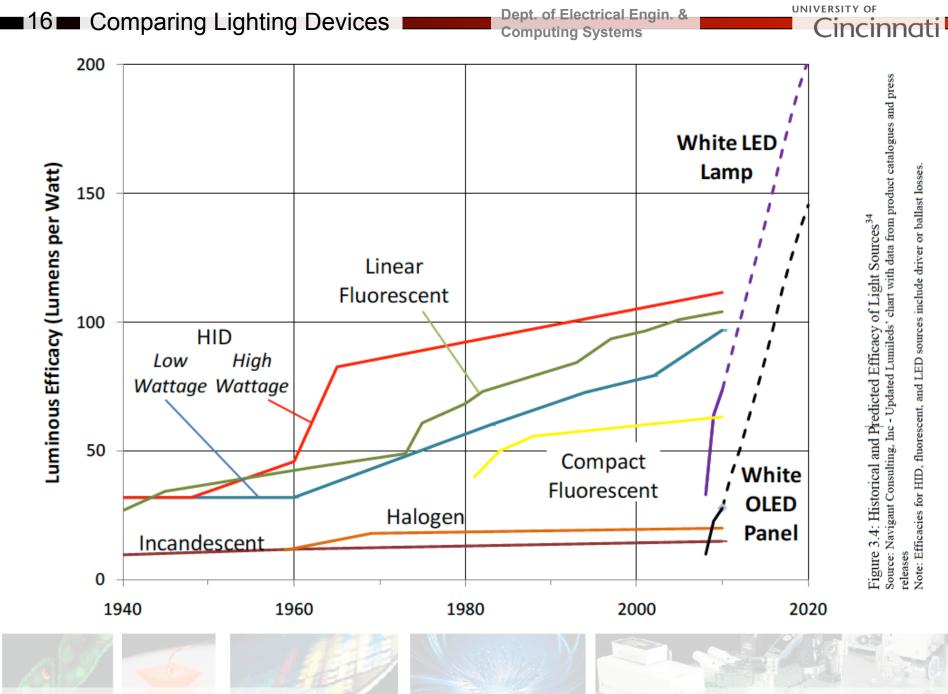
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▶ 1 W of 555 nm light (green) = 683 Lumens to the human eye. Scoto 2.5 * Blue: ~50 lm/W At 555 nm, * Green: ~>600 lm/W (rel) Photopic peak, * Red~250 lm/W 0.1 1 W = 683.0 m, Photopic=Scotopic 0.01 Questions: 1e-3 Why is the human eye adapted to green light? 1e-4 For a white light source, is the theoretical maximum 683 lm/W also? 1e-5 700 400 500 600 (nm)

> Credit: Alex Ryer – Light Meas. Handbook



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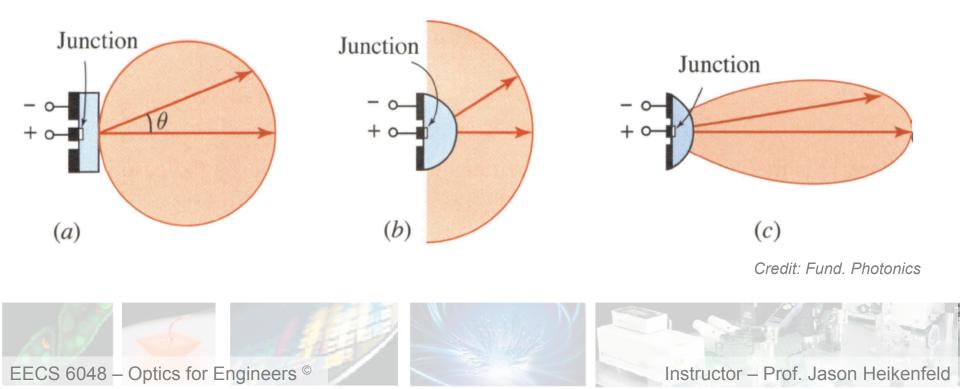
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17 Optics of LEDs	Computing Systems	Cincinnati

LEDs are isotropic emitters (photons are generated in ALL directions equally). However, refraction and total-internal reflection can change the radiation pattern as it exits a packaged LED!

Notice the flat LED at left (Lambertian profile, intensity (arrow length) decreases as cosine of angle).

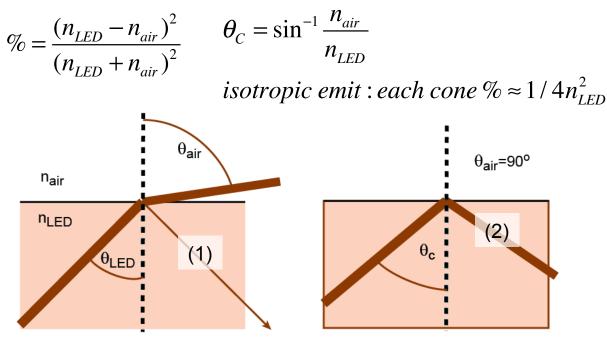
- Notice the hemispherical LED at center (it is isotropic, light undergoes no refraction at all).
- The LED at right uses a parabolic shape (more light in the forward direction).



18 Optics of LEDs

Dept. of Electrical Engin. & Computing Systems So for example, how much light escapes from a GaP LED?

(1) Fresnel reflection. (2) Total internal reflection (TIR)



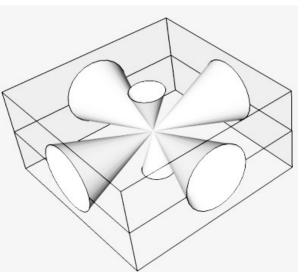
Example for GaP ($n \sim 3.4$): Fresnel % = (1-0.3) or 70% out ...

 θ_{C} =17° so 2% escapes at each of 6 sides ...

70% x 2% x 6 sides = 8.4% (at best!)

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So why is this LED shaped like an inverted pyramid? New popular approach is photonic crystals or lens arrays...

■19■ Optics of LEDs

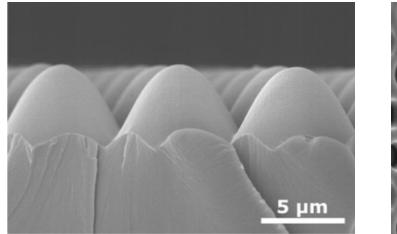
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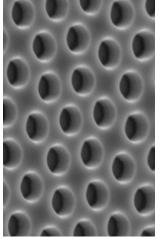
▶ Here is a derivation for out-coupling for LEDs and OLEDs, which are isotropic in radiation pattern (*credit Fund. Photonics*).

• The photon flux emitted along directions lying outside a cone of (critical) angle $\theta_c = \sin^{-1}(1/n)$, such as illustrated by ray *C*, suffers total internal reflection in an ideal material and is not transmitted [see (1.2-5)]. The area of the spherical cap atop this cone is $\mathbf{A} = \int_0^{\theta_c} 2\pi r \sin \theta r \, d\theta = 2\pi r^2 (1 - \cos \theta_c)$ while the area of the entire sphere is $4\pi r^2$. Thus, the fraction of the emitted light that lies within the solid angle subtended by this cone is $\mathbf{A}/4\pi r^2$, so that

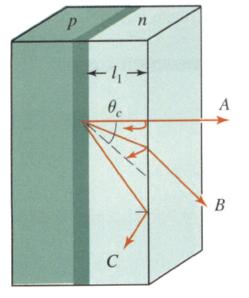
$$\eta_3 = \frac{1}{2}(1 - \cos\theta_c) = \frac{1}{2}\left(1 - \sqrt{1 - 1/n^2}\right) \approx 1/4n^2.$$
(17.1-21)

• At right are two techniques that are applied at the surface to improve outcoupling, one refractive, on diffractive, which is which?





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20 Optical Absorption (Beer-Lambert)

So what does the absorption look like?

► Are all the photons absorbed instantly at the surface? Do they penetrate a bit of distance before being absorbed? What does this look like?

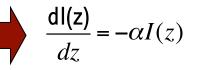
Some disciplines/books use log base 10 (not In base 2.303). Remember, you can go back and forth

 $e \times log(X) = ln(X)$

▶ Remember, if someone reports attenuation in dB it is 10 log (I/Io)... you only use "20 log" in cases such as circuits where you measure current and voltage because power is I²R or V²/R

$$|(z) - |(z + dz) = \alpha I(z) dz$$

 α = amount absorbed over dz



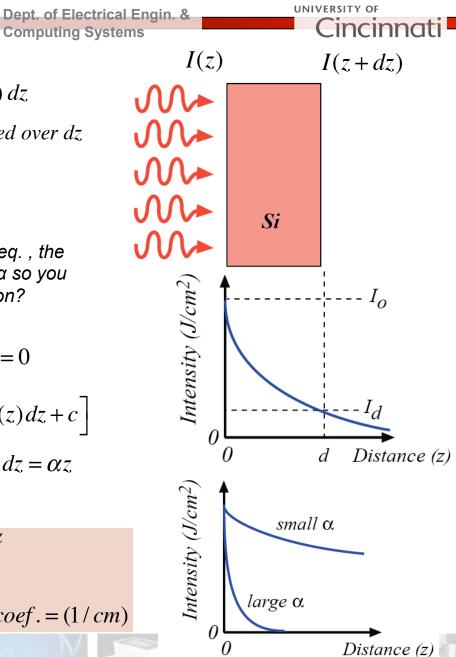
simple first order linear diff. eq. , the derivative is proportional to α so you can maybe guess the solution?

$$\frac{dI(z)}{dz} + \alpha I(z) = f(z) = 0$$

gen. sol. = $e^{-h} \left[\int e^{-h} f(z) dz + c \right]$
where $h = \int \alpha dz = \alpha z$

$$\therefore I(z) = I(0)e^{-\alpha Z}$$

 $\alpha = absorbtion \ coef. = (1 / cm)$



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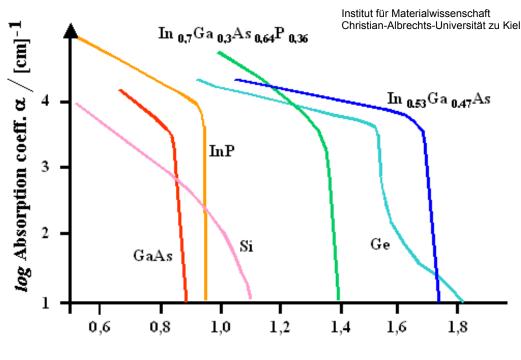
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21 Optical Absorption (Beer-Lambert)

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Wavelength λ_{vac} [μm]

• Example, how thick does a Si wafer need to be to absorb 90% of 1.0 μ m light? Assume α ~100 cm⁻¹ (is a bit less)

$$I(z) = I(0)e^{-\alpha Z}$$

$$\frac{I(z)}{I(0)} = 0.1 = e^{-100 \times Z} \quad \therefore z = \frac{\ln(0.1)}{-100} cm = 230 \,\mu m$$

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Same 90% calculation for green light (peak of sunlight spectrum), and z only ~2 µm!

■ 22 ■ Review! Take a break!

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- Light traveling into an absorbing medium decreases in intensity:
- (a) Quadratically.
- (b) Linearly.
- (c) Asymptotically.
- (d) Exponentially.
- Im/W is a unit of:
- (a) Optical power for 1W of light.
- (b) Brightness of 1 W of light as perceived by the human eye.
- (c) Brightness of a light regardless of wattage.
- (d) Outcoupling efficiency of an LED.
- Im/W in order of most efficient to least efficient (bright).
- (a) Blue / red / green.
- (b) Green / blue / red.
- (c) Green / red / blue.
- (d) Red / green / blue.

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Whew! Lets take a quick break!



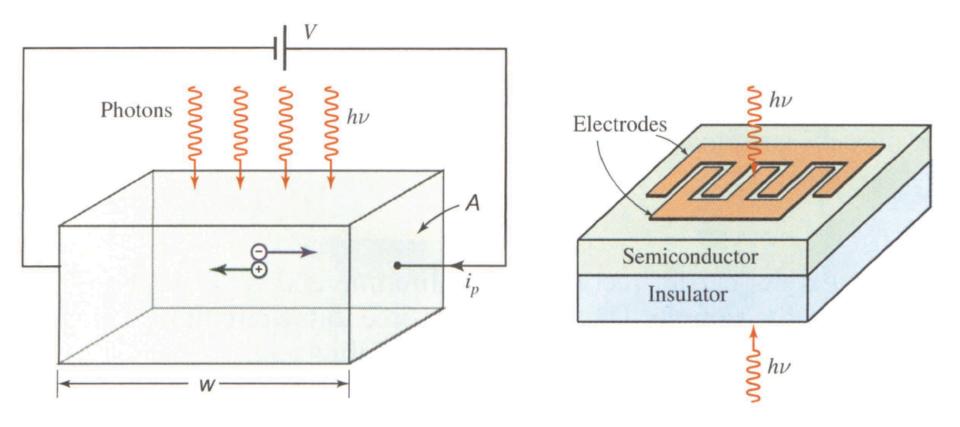


23 Switch Topics... Detectors!

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• Lets switch topics now... Detectors!

• One of simplest detectors is a photoconductive detector (main drawback is that background current is high in a semiconductor, so that limits the minimum sensitivity).



Credit: Fund. Photonics

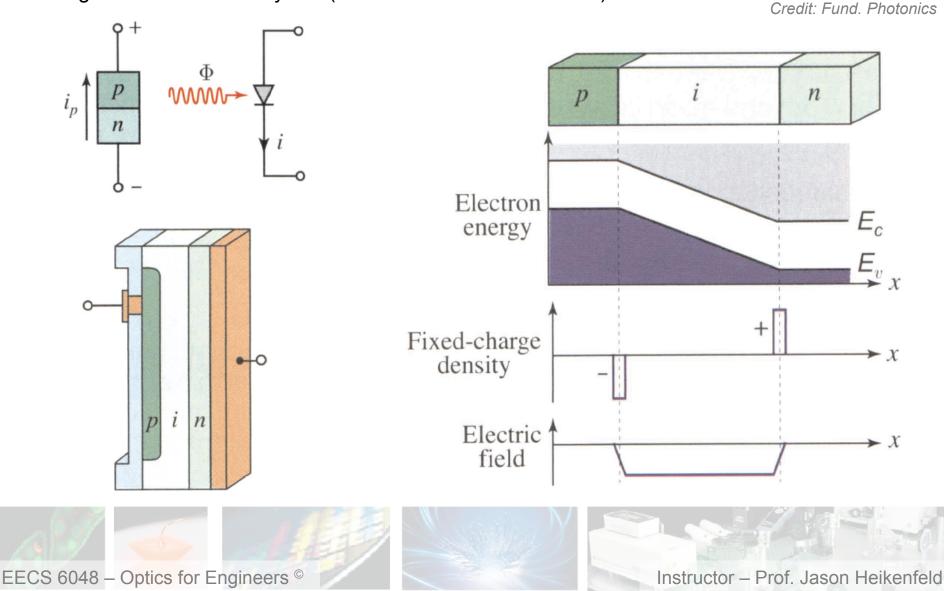


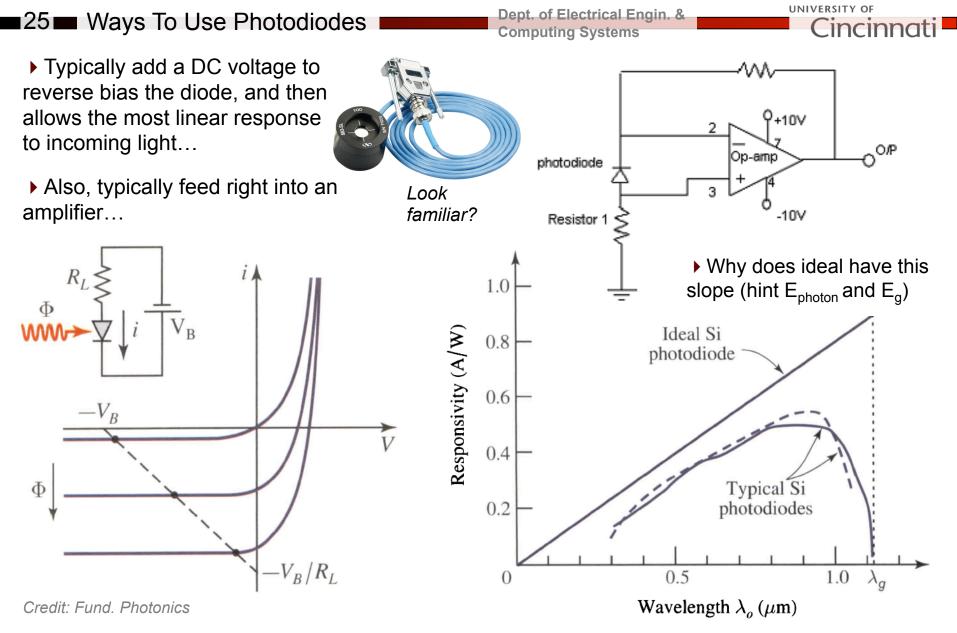
24 A Better Detector - Photodiode

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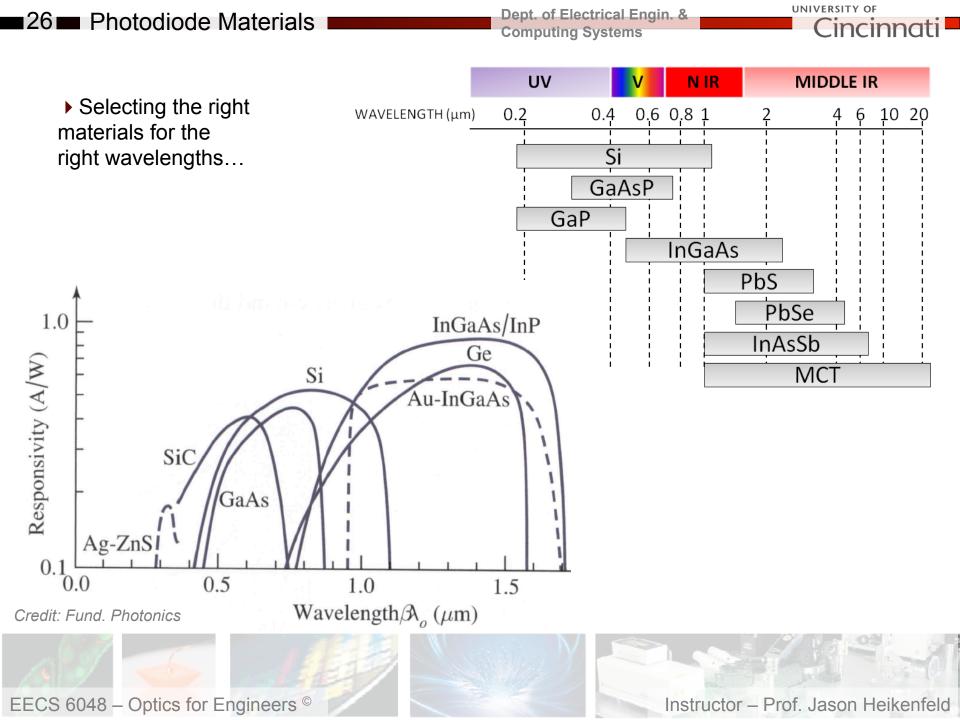
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- Photodiode, typically is reverse biased (as seen in diagram at right).
- Background current is very low (is reverse saturation current).





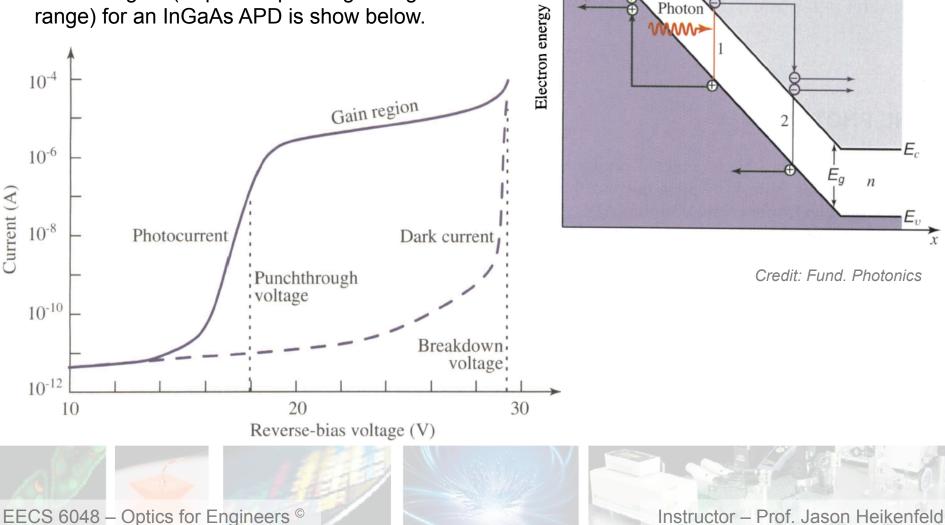






APD's are specially designed diodes that can handle a large reverse bias to create carrier multiplication (internal amplification!)

Gain region (requisite operating voltage) range) for an InGaAs APD is show below.

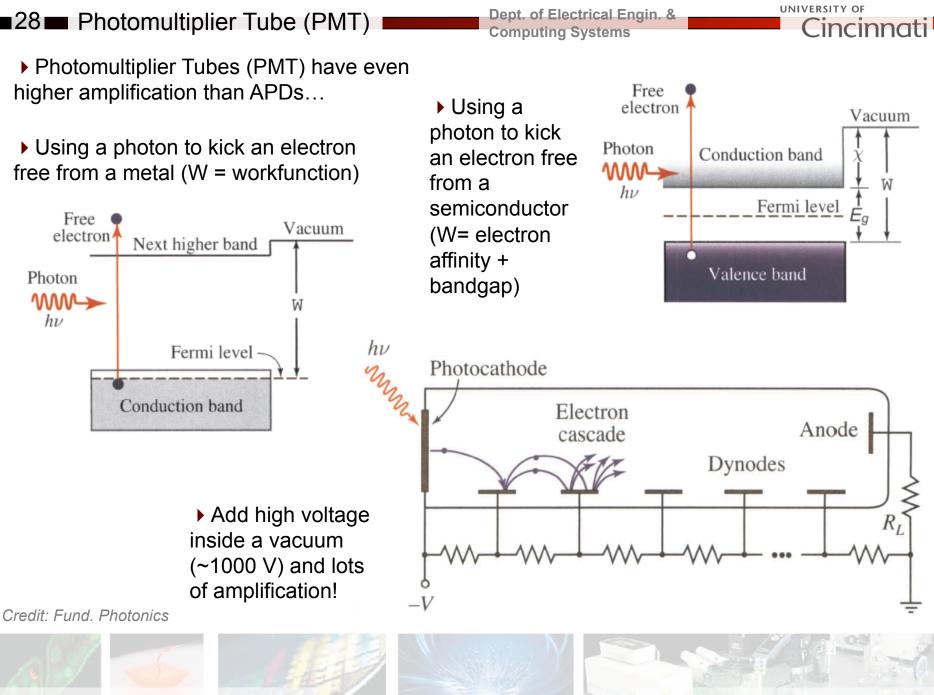


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29 Key Photodetector Metrics

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Dark Current: The DC current that flows through a detector when there is no light present. Usually measured in the nanoamp range.

NEP: The amount of optical input power that produces the same output level as the inherent noise level of the detector/receiver, i.e. a signal-to-noise ratio of one. Usually given in picowatts per root bandwidth. Total noise level is calculated by multiplying the NEP by the square root of the full bandwidth.

Power Bandwidth, -3 dB: The frequency at which the electrical output power of the detector falls to 50% of its value at DC. Same as "electrical" bandwidth. Typically used for specifying analog microwave detector bandwidths.

Responsivity, R: The sensitivity of a detector element to light given in amps/watt, independent of load resistance.

$$R = \eta \frac{q}{hv} = \frac{\# e's}{\# photons} \frac{1.6x10^{-19}C}{6.63x10^{-34}(J \cdot s)f(1/s)} \approx \eta \frac{\lambda(nm)}{1240} \quad A/W \qquad R_{\text{max}} = 2A/W \text{ for } 2eV$$

Rise Time: The 10–90% rise time of the output voltage step when the detector is illuminated by a negligibly short optical step function. This is difficult to do in practice, so the measurement is simulated mathematically by integrating the pulse width (see above).

Sensitivity: The optical input power (in dBm) required to achieve a particular Bit Error Rate, BER (or signal to noise ratio) at the output of the detector/receiver. Usually specified for BERs of 10⁻⁹ (or a S/N of 6). BERs of 10⁻¹² require a S/N=7.

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30 ■ Si Photodiodes (\$22)



No gain...

Silicon Detector, Normal Response, 0.81mm² NT57-507 Type Biased: Normal Response Borosilicate Window Operating Temperature (°C) -40 to 100 Typical Applications High light levels, pulse detectors, AC light measurement -10 Voltage Bias, V_{Bias} (V) Active Area (mm²) 0.81 Responsivity @ 970nm (A/W) 0.65 6.2 x 10⁻¹⁵ Noise Equivalent Power NEP (W/ Hz^{1/2}) 1.45 x 1013 @ -10V, 970nm Detectivity (cmHz^{1/2}/W) Terminal Capacitance (pF) 8 @ 0V; 2 @ 10V Dark Current Id (nA) 0.05 @ 10V Maximum Breakdown Voltage (V) 30 8 @ -10V/50Ω, 632nm Rise Time (ns) TO-18 Mount RoHS Compliant

When light, with enough energy to excite an electron from the valence to the conduction band, is incident upon the detector, the resulting accumulation of charge leads to a flow of current in an external circuit. Since light is not the only source of energy that can excite an electron, detectors will have some amount of current that is not representative of incident light. For example, fluctuations in thermal energy can easily be mistaken for light intensity changes. A variety of these "non-light" contributions are present and, when summed up, make up the total noise within the detector.



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■ 31 ■ Avalanche Photodiodes (\$169)

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Gain up to 100...

Si APD 1.0mm UV-VIS(200-1000nm)	NT58-261
Active Area Diameter (mm)	1.00
Spectral Response (nm)	200-1000
Photosensitivity S (A/W) @ λ_p	0.42
Quantum Efficiency QE (%) @ λ_p	80.00
Breakdown Voltage BDV, I_d =100µA (V)	150/200 (Typical/Maximum)
Temperature Coefficient of BDV (V/°C)	0.14
Dark Current I _d (nA)	0.20/5.0 (Typical/Maximum)
Response Time (ns) $R_L=50\Omega$	1.40
Gain (M)	50.00
Terminal Capacitance (pF)	15.00
Mount	TO-18
Operating Temperature (°C)	-20 to 60
RoHS	Compliant

As with a conventional photodiode, absorption of incident photons creates electron-hole pairs. A high reverse bias voltage creates a strong internal electric field, which accelerates the electrons through the silicon crystal lattice and produces secondary electrons by impact ionization. The resulting electron avalanche can produce gain factors up to several hundred.

Si APDs are used when light signals are too high for photomultiplier tubes and too low for conventional photodiodes. Si APDs are often used in high-speed applications since the excess noise from the avalanche process is still lower than the noise that would be generated in connecting an external amplifier to a conventional photodiode operated at high frequencies.

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32 Photomultiplier Tube (\$895)





Gain up to 10⁶...

Why is cathode responsivity 10X worse than a photodiode but anode 10⁵X higher than a photodiode responsivity?

3.7 x 13.0mm Current Output Type PMT	Module (185-750nm) NT66-274
Model Number	H9305-01
Dimensions (mm)	50.8 x 13 x 53.2
Input Current (mA)	7
Input Voltage (V)	± 11.5 to ± 15.5
Control Voltage (V)	+0.25,+0.9,+1.0
Radiant Sensitivity - Anode	7.4×10 ⁵ A/W
Radiant Sensitivity - Cathode (mA/W)	90
Peak Response Wavelength (nm)	420
Spectral Response (nm)	185-750
Sensitivity Adjustment	1:104
Output Signal	10 µA
Ripple (mV)	0.5
Active Area (mm)	3.7x13.0
Dark Current I _d (nA)	0.4/1
Settling Time (seconds)	10
Rise Time (ns)	1.4
Operating Temperature (°C)	+5 to +50
Storage Temperature (°C)	-20 to +50
Weight (g)	110
RoHS	Exempt

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When light enters the photocathode of a photomultiplier tube, photoelectrons are emitted from the photocathode. These photoelectrons are multiplied by secondary electron emission through the dynodes and then collected by the anode as an output pulse. PMTs generally operate 500V to about 1200V DC or higher. Warning: This product is extremely light sensitive. Exposing aperture to room light will permanently damage product. Should only be used with sources less than 1 nano-watt.



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33 ■ Review! Complete!

• Which ordering is correct from least to most sensitive for light:

- (a) APD / photodiode / PMT / photoconductor.
- (b) photodiode / APD / PMT / photoconductor.
- (c) photodiode / APD / photoconductor / PMT.
- (d) photoconductor / photodiode / APD / PMT.
- The detectors we use in this lab are:
- (a) Photoconductors.
- (b) Photodiodes.
- (c) APDs.
- (d) PMTs.



Complete!

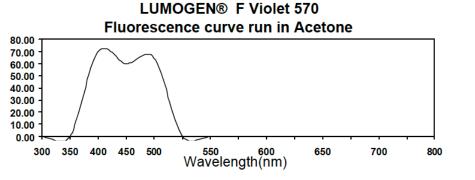


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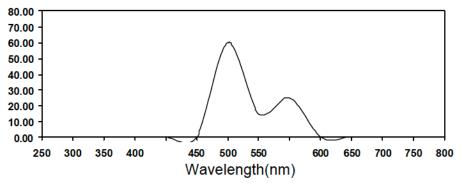
Cincinnati

■ 34 ■ Examples – Lumogen Dyes

Cincinnati

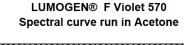


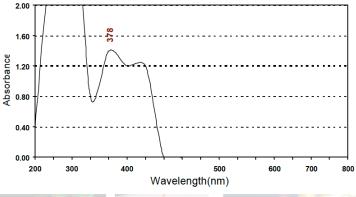
LUMOGEN® F Orange 240 Fluorescence curve run in Acetone



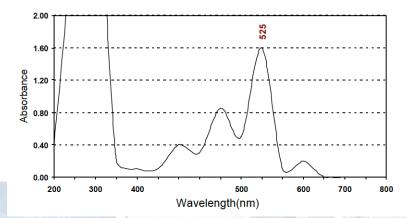
Max (nm) Absorption in ethylene dichloride	Max (nm) Absorption in PMMA	Fluorescence (nm) in ethylene dichloride	Max Quantum Yield
524	525	539	0.99

Max (nm) Absorption in ethylene dichloride	Max (nm) Absorption in PMMA	Fluorescence (nm) in ethylene dichloride	Max Quantum Yield
378	378	413	0.94





LUMOGEN® F Orange 240 Spectral curve run in Acetone



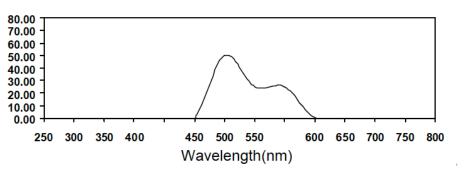
Instructor – Prof. Jason Heikenfeld

EECS 6048 – Optics for Engineers ©

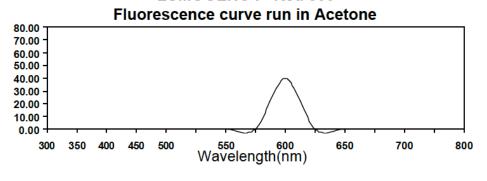
■ 35 ■ Examples – Lumogen Dyes

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LUMOGEN® F Yellow 083 Fluorescence curve run in Acetone



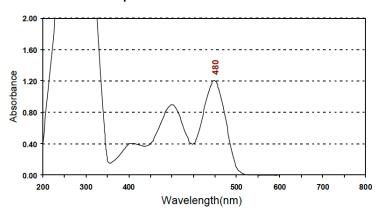
Max (nm) Absorption	Max (nm) Absorption	Fluorescence	Max(nm Quantum
in ethylene dichloride	in PMMA	in ethylene dichloride	Yield
476	473	490	0.91



LUMOGEN® F Red 300

Max (nm) Absorption in ethylene dichloride dichloride	Max (nm) Absorption in PMMA	Fluorescence (nm) in ethylene dichloride	Max Quantum Yield
578	578	613	0.98

LUMOGEN® F Yellow 083 Spectral curve run in Acetone





LUMOGEN® F RED 300 Spectral curve run in Acetone

